#### TOSHIBA Photocoupler GaAs Ired & Photo-Triac

TLP3526

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:

Anode

N.C.

Cathode

Triac T2

Triac T1

Triac gate

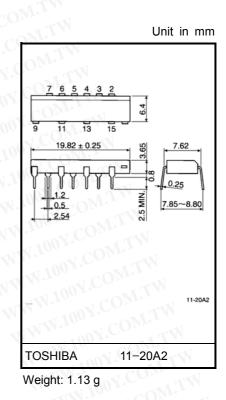
Triac Driver Programmable Controllers AC-Output Module Solid State Relay

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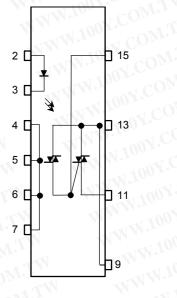
The TOSHIBA TLP3526 consists of a photo-triac optically coupled to a gallium arsenide infrared emitting diode in a 16 lead plastic DIP.

- Peak off-state voltage: 600V(min.)
- Trigger LED current: 10mA(max.)
- On-state current: 1.0A<sub>rms</sub>(max.)
- Isolation voltage: 2500 V<sub>rms</sub>(min.)
- UL recognized: UL1577, file no. E67349

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### Pin Configuration (top view)



|          | Characteristic                                  | OMIT               | Symbol               | Rating  | Unit             |
|----------|---|--------------------|----------------------|---------|------------------|
| -1       | Forward current                                 | OM.TH              | IF                   | 50      | mA               |
|          | Forward current derating (Ta                    | a ≥ 53°C)          | ΔI <sub>F</sub> / °C | -0.7    | mA / °C          |
| LED      | Peak forward current (100µ                      | s pulse, 100pps)   | I <sub>FP</sub>      | W.M.    | A                |
| TN       | Reverse voltage                                 | Y.COM.TW           | V <sub>R</sub>       | 5       | V                |
|          | Junction temperature                            | OY.COM.TY          | Тј                   | 125     | °C               |
|          | Off-state output terminal vo                    | Itage              | VDRM                 | 600     | v                |
|          | On-state RMS current                            | Ta = 40°C          |                      | 1.0     | Nov.Co           |
| $0_{M}$  |   | Ta = 60°C          | I <sub>T(RMS)</sub>  | 0.7     | A<br>A<br>C      |
| Detector | On-state current derating (1                    | a ≥ 40°C)          | ΔI <sub>T</sub> / °C | -14.3   | mA / °C          |
| Det      | Peak current from snubber (100µs pulse, 120pps) | circuit            | I <sub>SP</sub>      | 2       | А                |
|          | Peak nonrepetitive surge cu                     | rrent (50Hz, peak) | ISTM                 | 10      | A                |
| N.(      | Junction temperature                            | WW. Many.C         | Tj                   | 110     | °C               |
| Storag   | ge temperature range                            | VWW.IOMY           | T <sub>stg</sub>     | -40~125 | °C               |
| Opera    | ting temperature range                          | WW.IOO             | T <sub>opr</sub>     | -20~80  | °C               |
| ead s    | soldering temperature (10 s)                    | WW.100             | T <sub>sol</sub>     | 260     | °C               |
| Isolati  | on voltage (AC, 1min., R.H.≤ 6                  | 60%) (Note)        | BVS                  | 2500    | V <sub>rms</sub> |

(Note 1) Device considered a two terminal: LED side pins shorted together and detector side pins shorted together. W.100Y.COM

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### **Recommended Operating Conditions**

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| Characteristic                    | Symbol           | Min. | Тур.           | Max. | Unit |
|-----------------------------------|------------------|------|----------------|------|------|
| Supply voltage                    | V <sub>AC</sub>  |      | <u>) 147.</u>  | 240  | Vac  |
| Forward current                   | JE VIE           | 15   | 20             | 25   | mA   |
| Peak current from snubber circuit | I <sub>SP</sub>  | 100- | $c_{\Theta_N}$ | 1    | А    |
| Operating temperature             | T <sub>opr</sub> | -20  | . – )]         | 80   | °C   |

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# Individual Electrical Characteristics (Ta = 25°C)

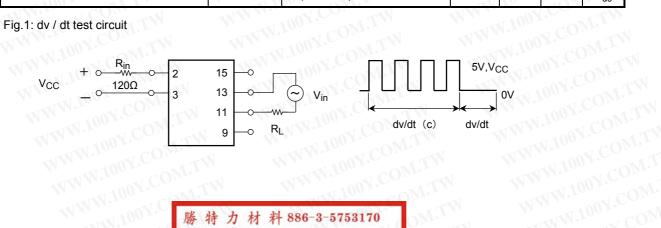
|          | Characteristic                               | Symbol          | Test Condition  | Min.             | Тур.       | Max. | Unit |
|----------|--|-----------------|---|------------------|------------|------|------|
| đ        | Forward voltage                              | V <sub>F</sub>  | I <sub>F</sub> = 10mA   | 1.0              | 1.15       | 1.3  | V    |
| Ð        | Reverse current                              | IR              | V <sub>R</sub> = 5V   |                  | _          | 10   | μA   |
|          | Capacitance                                  | CT              | V = 0, f = 1MHz   | 1.               | 30         | _    | pF   |
| LN.      | Peak off-state current                       | IDRM            | V <sub>DRM</sub> = 600V, Ta = 110°C   | Γ.T.W            | _          | 100  | μA   |
|          | Peak on-state voltage                        | V <sub>TM</sub> | I <sub>TM</sub> = 1.5A  | N.T.V            | _          | 3.0  | V    |
| ctor     | Holding current                              | IH T            | R <sub>L</sub> = 100Ω   | TTA              | <li>N</li> | 25   | mA   |
| Detector | Critical rate of rise of off-state voltage   | dv / dt         | V <sub>in</sub> = 240V <sub>rms</sub> (Fig.1)                               | 01/              | 500        | _    | V/µ  |
|          | Critical rate of rise of commutating voltage | dv / dt(c)      | V <sub>in</sub> = 240V <sub>rms</sub> , I <sub>T</sub> = 1.0Arms<br>(Fig.1) | c <del>o</del> M | 5          | _    | V/µ: |

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## WWW.100Y Coupled Electrical Characteristics (Ta = 25°C)

| Characteristic                   | Symbol         | Test Condition               | Min.               | Тур.             | Max.      | Unit             |
|----------------------------------|----------------|------------------------------|--------------------|------------------|-----------|------------------|
| Trigger LED current              | (FT            | V <sub>T</sub> = 6V          | 100Y.              | No.              | 10        | mA               |
| Capacitance<br>(input to output) | CS             | V <sub>S</sub> = 0, f = 1MHz | WW.100Y            | 1.5              | 1.14      | pF               |
| Isolation resistance             | R <sub>S</sub> | V <sub>S</sub> = 500V        | 5×10 <sup>10</sup> | 10 <sup>14</sup> | W-        | Ω                |
| NI 100X. ONITH V                 | 100            | AC, 1 minute                 | 2500               |                  | $0^{M.1}$ | M                |
| solation voltage                 | BVS            | AC, 1 second, in oil         | 1.12               | 5000             | MTO-      | V <sub>rms</sub> |
|                                  | WWW.           | DC, 1 minute, in oil         | ANN.               | 5000             |           | V <sub>dc</sub>  |

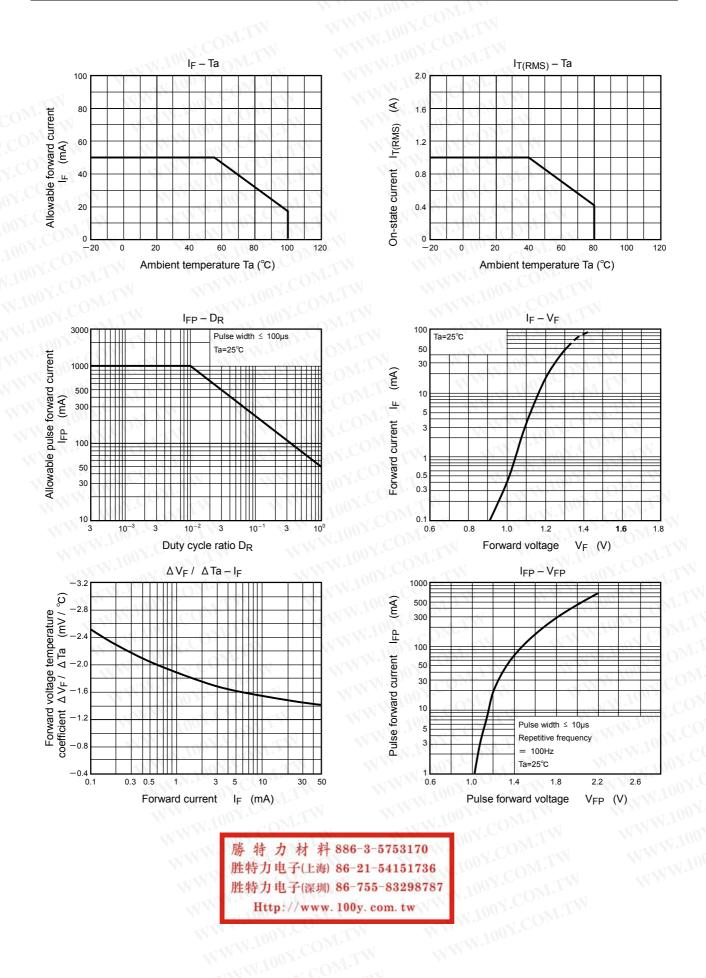


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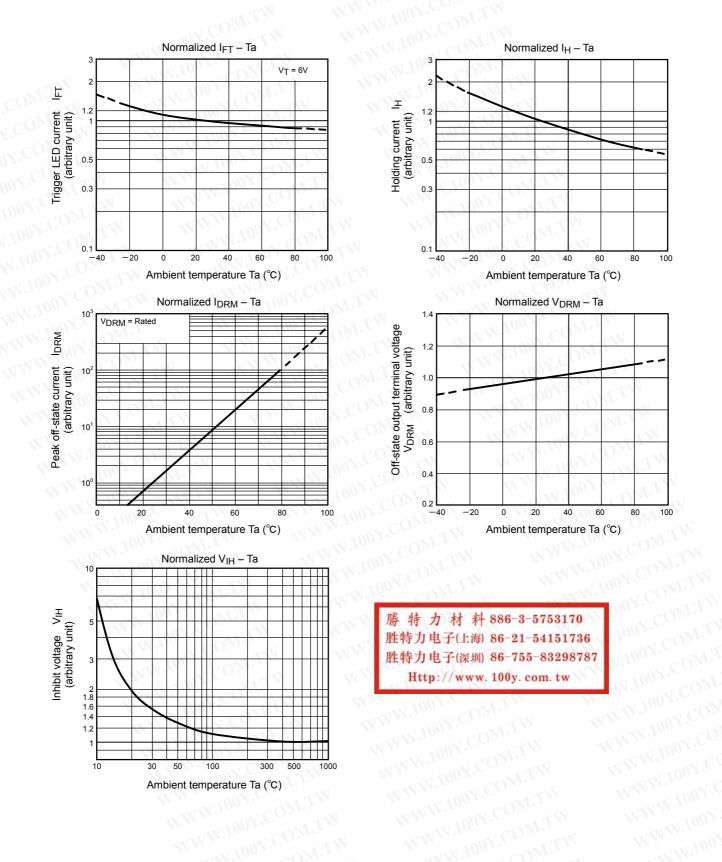
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